

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- Rectification
- Free-wheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V_{DRM} and V_{DRM} V	Conditions
DS2106SY40	4000	$V_{RSM} = V_{RRM} + 100V$
DS2106SY39	3900	
DS2106SY38	3800	
DS2106SY37	3700	
DS2106SY36	3600	
DS2106SY35	3500	

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DS2106SY37 for a 3700V device in a Y outline

or

DS2106SV37 for a 3700V device in a V outline

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

KEY PARAMETERS

V_{RRM}	4000V
$I_{F(AV)}$	3830A
I_{FSM}	62500A

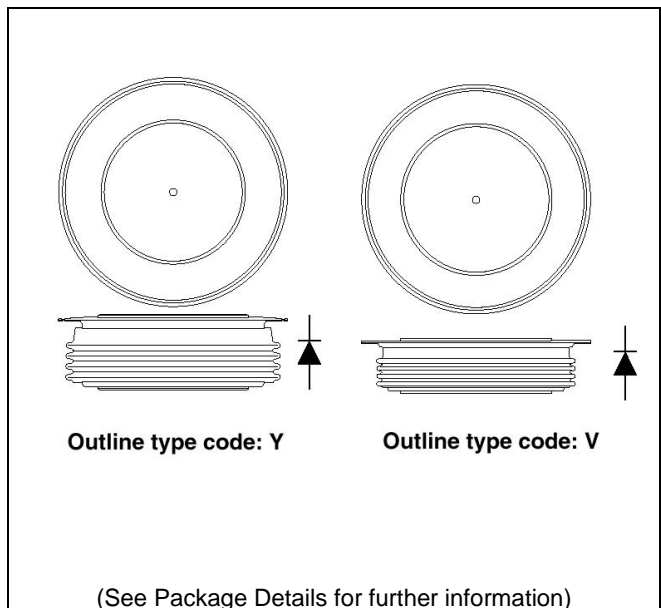


Fig. 1 Package outlines

CURRENT RATINGS

T_{case} = 75° C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Side Cooled				
I _{F(AV)}	Mean forward current	Half wave resistive load	3830	A
I _{F(RMS)}	RMS value	-	6016	A
I _F	Continuous (direct) on-state current	-	5597	A
Double Side Cooled (Anode side)				
I _{F(AV)}	Mean forward current	Half wave resistive load	2525	A
I _{F(RMS)}	RMS value	-	3966	A
I _F	Continuous (direct) on-state current	-	3421	A

T_{case} = 100° C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Side Cooled				
I _{F(AV)}	Mean forward current	Half wave resistive load	2850	A
I _{F(RMS)}	RMS value	-	4475	A
I _F	Continuous (direct) on-state current	-	4190	A
Double Side Cooled (Anode side)				
I _{F(AV)}	Mean forward current	Half wave resistive load	1920	A
I _{F(RMS)}	RMS value	-	3014	A
I _F	Continuous (direct) on-state current	-	2500	A

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I_{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$	50.0	kA
I^2t	I^2t for fusing	$V_R = 50\% V_{RRM} - \frac{1}{4}$ sine	12.5	MA ² s
I_{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$	62.5	kA
I^2t	I^2t for fusing	$V_R = 0$	19.6	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	Min.	Max.	Units	
$R_{th(j-c)}$	Thermal resistance – junction to case	Double side cooled	DC	-	0.0095	$^{\circ}C/W$
		Single side cooled	Anode DC	-	0.019	$^{\circ}C/W$
			Cathode DC	-	0.019	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance – case to heatsink	Clamping force 43kN (with mounting compound)	Double side	-	0.002	$^{\circ}C/W$
			Single side	-	0.004	$^{\circ}C/W$
T_{vj}	Virtual junction temperature	On-state (conducting)		-	160	$^{\circ}C$
		Reverse (blocking)		-	150	$^{\circ}C$
T_{stg}	Storage temperature range		-55	150	$^{\circ}C$	
F_m	Clamping force		38.0	47.0	kN	

CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 3000A peak, T _{case} = 25° C	-	1.15	V
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 150° C	-	250	mA
Q _S	Total stored charge	I _F = 2000A, di _{RR} /dt = 3A/μs	-	5000	μC
I _{rr}	Peak reverse recovery current	T _{case} = 150° C, V _R = 100V	-	150	A
V _{TO}	Threshold voltage	At T _{vj} = 150° C	-	0.75	V
r _T	Slope resistance	At T _{vj} = 150° C	-	0.118	mΩ

CURVES

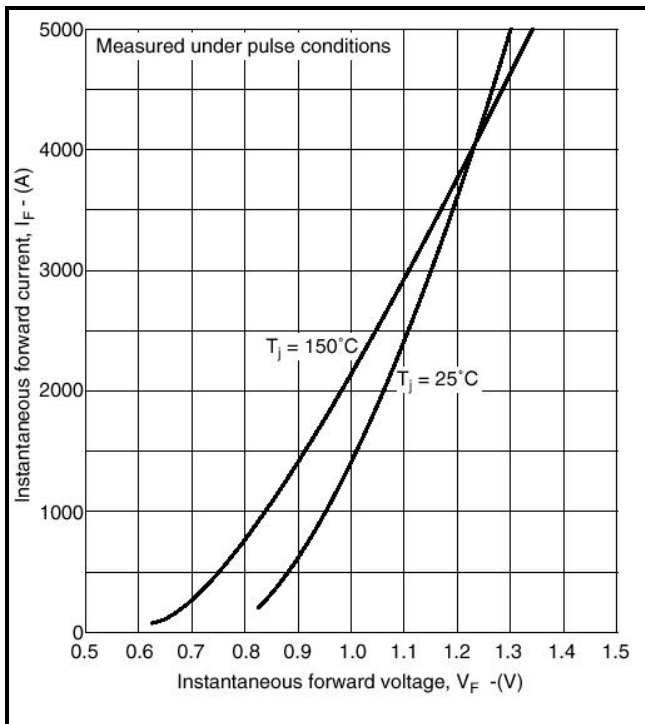


Fig.2 Maximum & minimum on-state characteristics

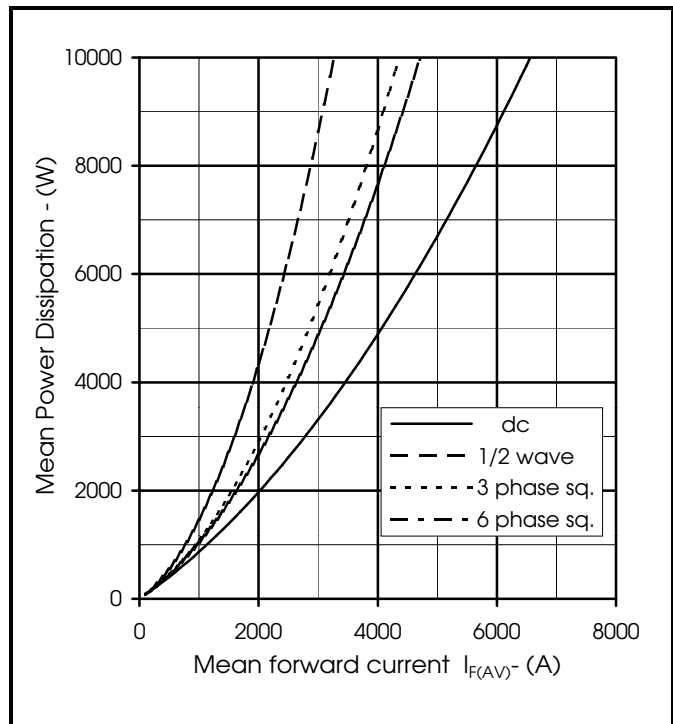


Fig.3 Dissipation curves

V_{TM} EQUATION

$$V_{TM} = A + B \ln(I_T) + C \cdot I_T + D \cdot \sqrt{I_T}$$

Where A = - 0.15357
 B = 0.177571
 C = 0.000179
 D = - 0.01294

these values are valid for T_j = 150° C for I_F 500A to 5000A

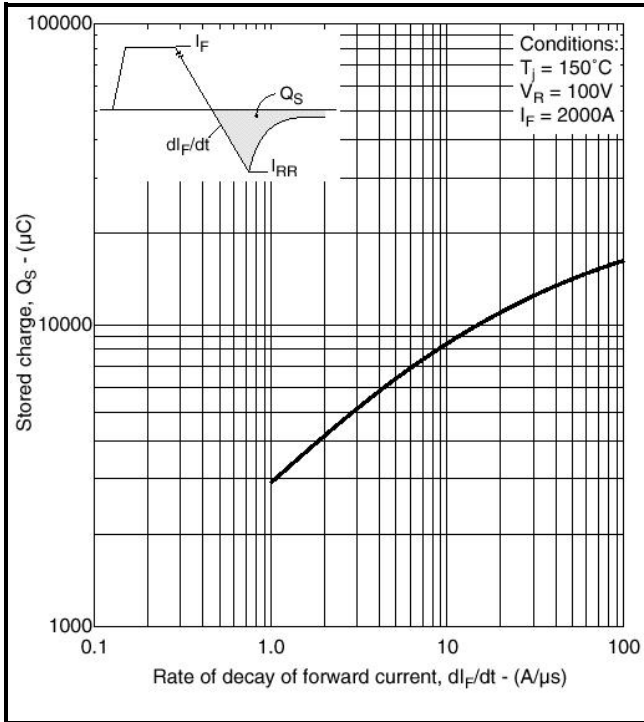


Fig.4 Total stored charge

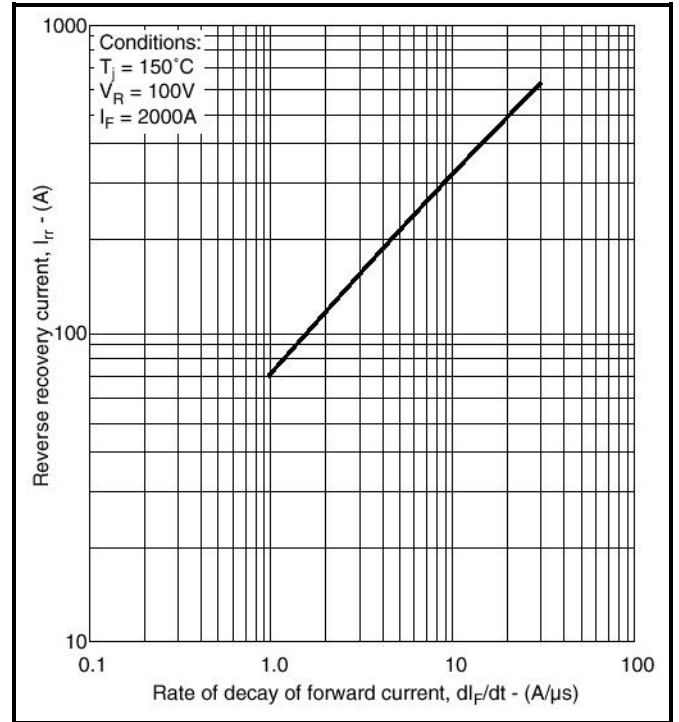


Fig.5 Maximum reverse recovery current

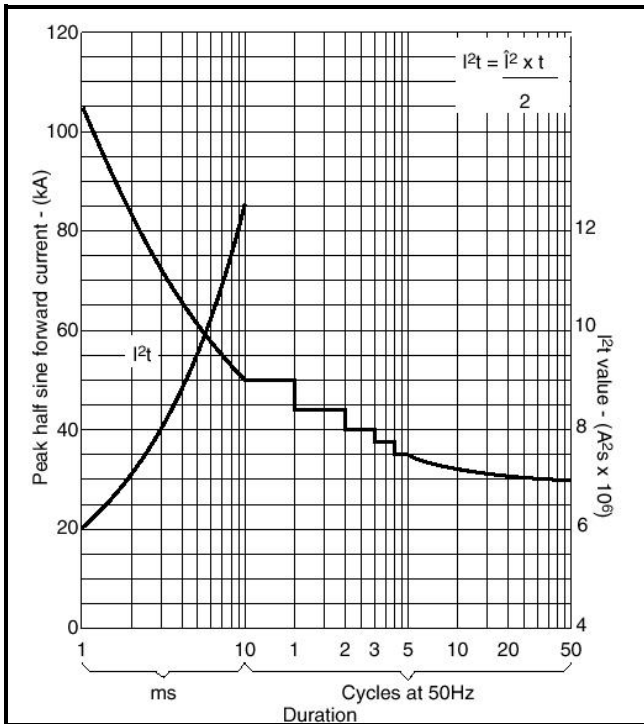


Fig.6 Surge (non-repetitive) forward current vs time (with 50% V_{RRM} at $T_{case} 150^\circ\text{C}$)

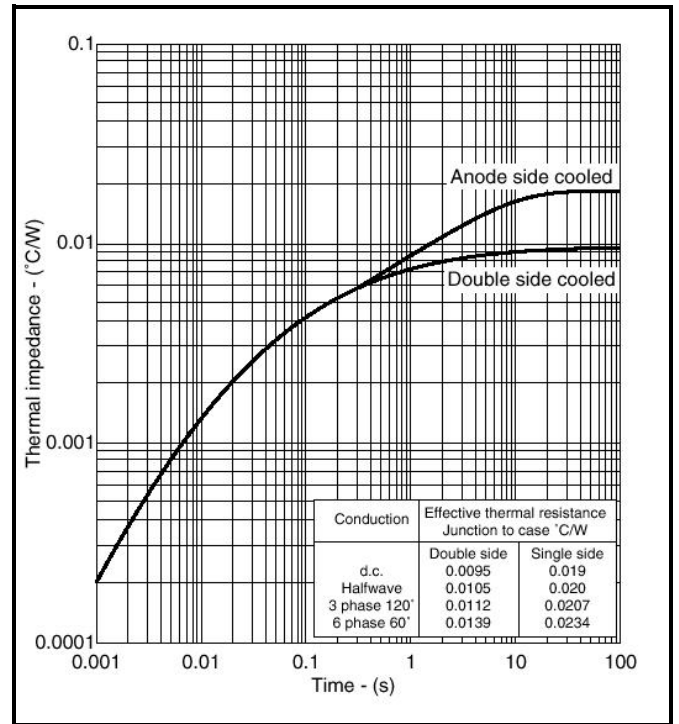
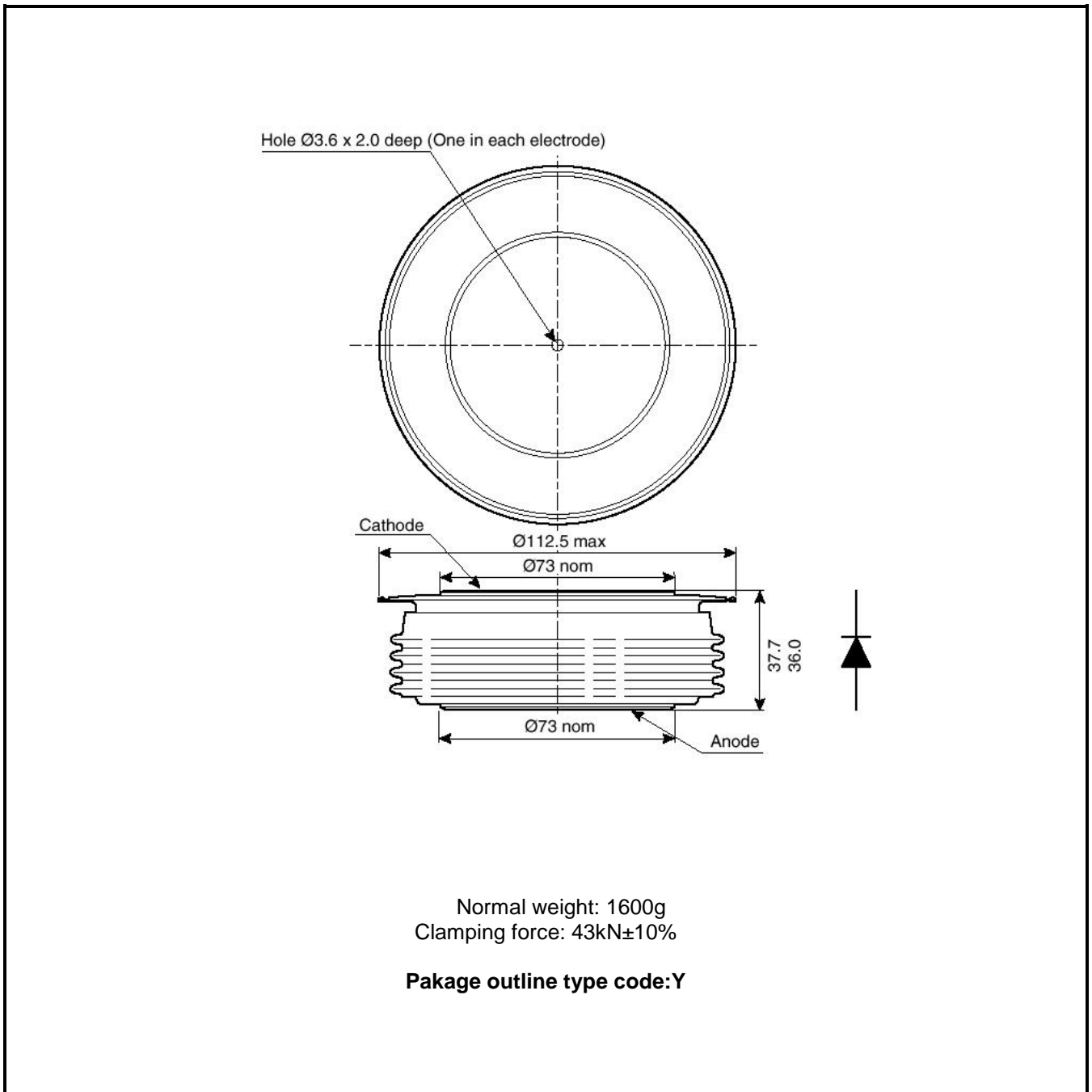


Fig.7 Maximum (limit) transient thermal impedance-junction to case

PACKAGE DETAILS

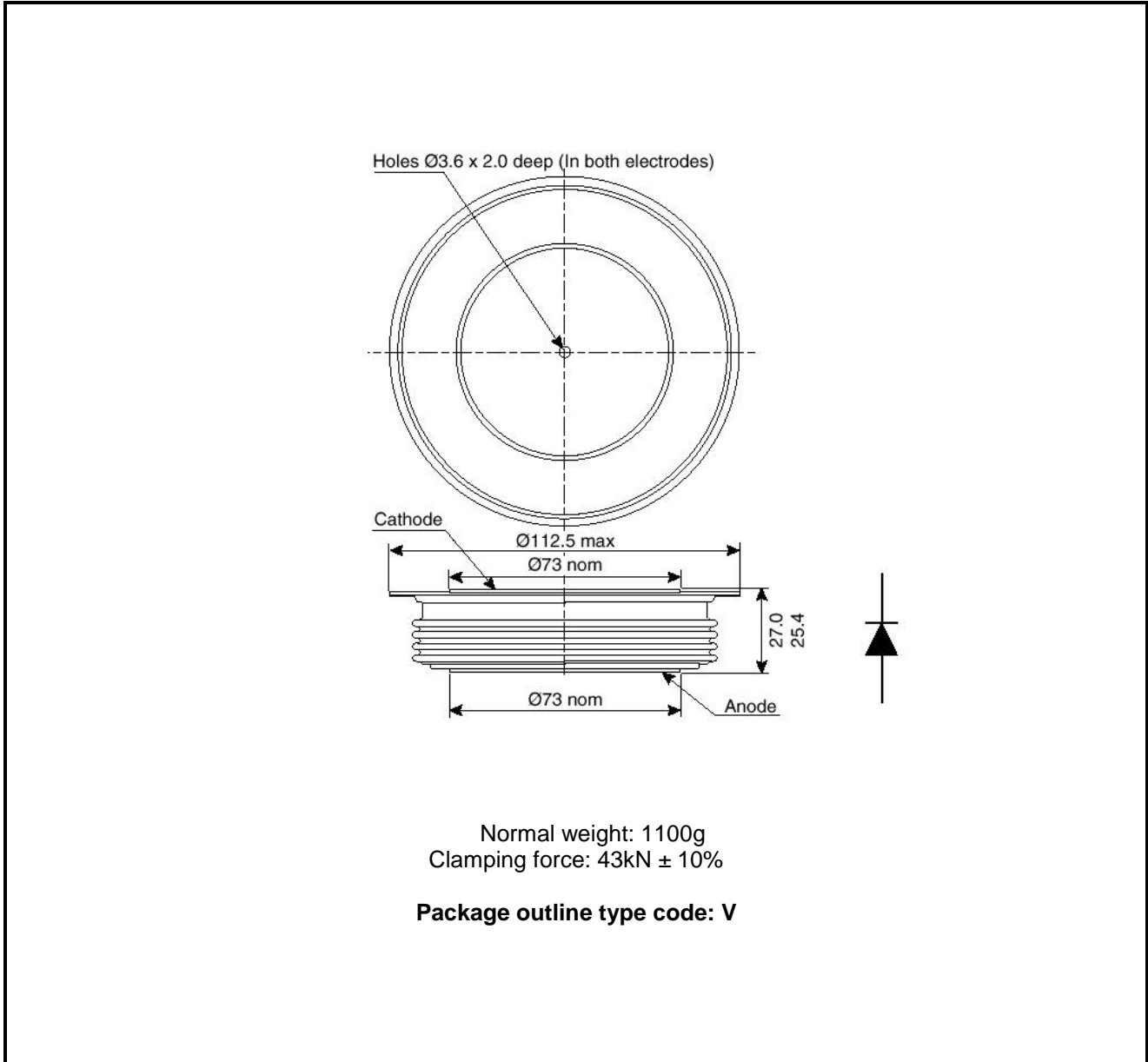
For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:
Some packages may be supplied with gate and or tags.

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POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.

Stresses above those listed in this data sheet may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed.



<http://www.dynexsemi.com>

e-mail: power_solutions@dynexsemi.com

HEADQUARTERS OPERATIONS DYNEX SEMICONDUCTOR LTD

Doddington Road, Lincoln
Lincolnshire, LN6 3LF. United Kingdom.
Tel: +44(0)1522 500500
Fax: +44(0)1522 500550

CUSTOMER SERVICE

Tel: +44(0)1522 502753 / 502901. Fax: +44(0)1522 500020

SALES OFFICES

Benelux, Italy & Switzerland: Tel: +33(0)1 64 66 42 17. Fax: +33(0)1 64 66 42 19

France: Tel: (01) 60 69 32 36, (02) 47 55 75 53

Fax: (01) 60 69 31 97, (02) 47 55 75 59

Germany, Northern Europe, Spain & Rest of World:

Tel: +44(0)1522 502753 / 502901. Fax: +44(0)1522 500020

North America: Tel: (440) 259 2060. Fax: (440) 259 2059.

Tel: (949) 733 3005. Fax: (949) 733 2986.

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